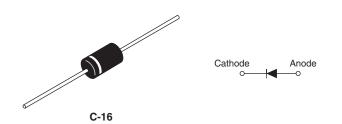
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Schottky Rectifier, 3.3 A



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PRODUCT SUMMARY					
Package	DO-201AD (C-16)				
I _{F(AV)}	3.3 A				
V _R	90 V, 100 V				
V _F at I _F	See Electrical table				
I _{RM} max.	3.0 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	3.0 mJ				

FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



HALOGEN

FREE Available

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-31DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	3.3	A			
V _{RRM}		90/100	V			
I _{FSM}	t _p = 5 μs sine	210	A			
V _F	3 Apk, T _J = 25 °C	0.85	V			
TJ		- 40 to 150	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-31DQ09	VS-31DQ09-M3	VS-31DQ10	VS-31DQ10-M3	UNITS		
Maximum DC reverse voltage	V _R							
Maximum working peak reverse voltage	V _{RWM}	90	90	100	100	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_L = 108 °C, rectangular waveform		3.3			
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	210	A		
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	34			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 6 mH		3.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
	V _{FM} ⁽¹⁾	3 A	T.I = 25 °C	0.85	V	
Maximum forward voltage drop		6 A	1j=23 0	0.97		
See fig. 1		3 A	T 105 %O	0.69		
		6 A	T _J = 125 °C	0.80		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	mA	
See fig. 4	IRM ()	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	3		
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		110	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 9.0			nH	
Maximum voltage rate of charge	dV/dt	Rated V _R 10 000 V/			V/µs	

Note

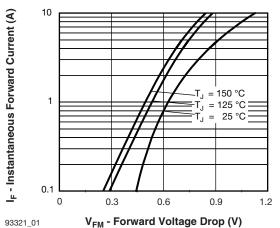
⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation Without cooling fin	80	°C/W		
Typical thermal resistance, junction to lead	R _{thJL}	DC operation	15	°C/W		
Approvimeto weight			1.2	g		
Approximate weight			0.042	oz.		
Marking device			31DQ09			
		Case style C-16	31DQ10			

Note

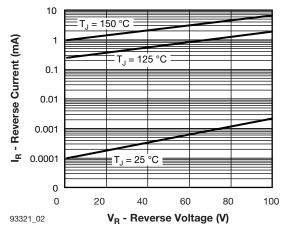
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

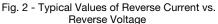
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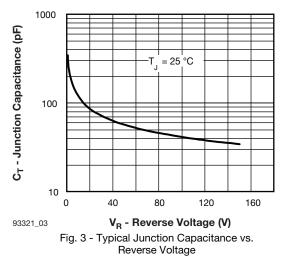


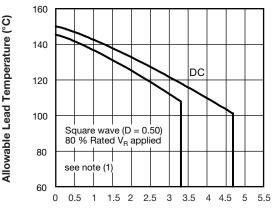
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Fig. 1 - Maximum Forward Voltage Drop Characteristics









93321_04 **I_{F(AV)} - Average Forward Current (A)** Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current

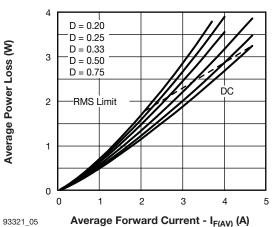
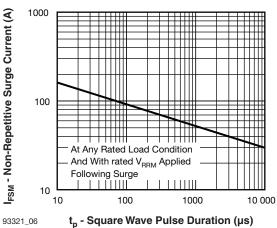


Fig. 5 - Forward Power Loss Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJL}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

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VISHA

Device code	VS-	31	D	Q	10	TR	-M3	
		2	3	4	5	6	7	I
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	31 = D = 1 Q = 10 = • TR • No Envi	Current DO-201 Schottky Voltage = Tape ne = Bu ronment	iconduct t Rating, packag y Q ser ratings and ree lk packa tal digit ad (Pb)-	, 3.3 A e ries el packa	ge	complia	09 = 90 V 10 = 100 V
				, ,			•	d terminations lead (Pb)-fre

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-31DQ09	500	500	Bulk			
VS-31DQ09TR	1200	1200	Tape and reel			
VS-31DQ09-M3	500	500	Bulk			
VS-31DQ09TR-M3	1200	1200	Tape and reel			
VS-31DQ10	500	500	Bulk			
VS-31DQ10TR	1200	1200	Tape and reel			
VS-31DQ10-M3	500	500	Bulk			
VS-31DQ10TR-M3	1200	1200	Tape and reel			

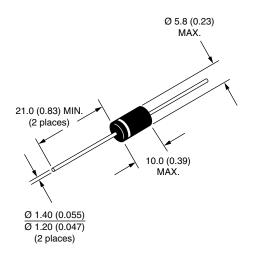
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95242				
Part marking information	www.vishay.com/doc?95304				
Packaging information	www.vishay.com/doc?95338				
SPICE model	www.vishay.com/doc?95300				

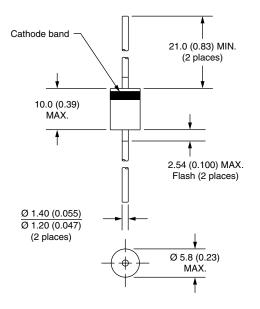




Axial DO-201AD (C-16)

DIMENSIONS in millimeters (inches)







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